

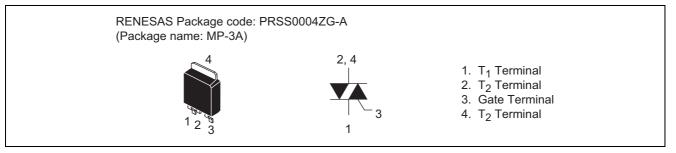
Triac Medium Power Use

> REJ03G0289-0400 Rev.4.00 Dec 19, 2008

## Features

- $I_{T(RMS)}$ : 5 A
- V<sub>DRM</sub> : 600 V
- $I_{FGT I}$ ,  $I_{RGT I}$ ,  $I_{RGT III}$ : 30 mA

## Outline



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Non-Insulated Type

Planar Passivation Type

## Applications

Hybrid IC, solid state relay, switching mode power supply, light dimmer, electric fan, electric blanket, control of household equipment such as washing machine, and other general purpose control applications

## **Maximum Ratings**

Parameter	Symbol	Voltage class	Unit	
raiameter	Symbol	12		
Repetitive peak off-state voltage <sup>Note1</sup>	V <sub>DRM</sub>	600	V	
Non-repetitive peak off-state voltage <sup>Note1</sup>	V <sub>DSM</sub>	720	V	

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I <sub>T(RMS)</sub>	5	A	Commercial frequency, sine full wave $360^{\circ}$ conduction, Tc = $103^{\circ}C^{Note3}$
Surge on-state current	I <sub>TSM</sub>	50	A	60Hz sinewave 1 full cycle, peak value, non-repetitive
l <sup>2</sup> t for fusing	l <sup>2</sup> t	10.4	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P <sub>GM</sub>	3	W	
Average gate power dissipation	P <sub>G(AV)</sub>	0.3	W	
Peak gate voltage	V <sub>GM</sub>	10	V	
Peak gate current	I <sub>GM</sub>	2	А	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass	—	0.26	g	Typical value

Notes: 1. Gate open.

## **Electrical Characteristics**

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	I <sub>DRM</sub>		—	2.0	mA	Tj = 125°C, V <sub>DRM</sub> applied
On-state voltage		V <sub>TM</sub>	_	—	1.8	V	$Tc = 25^{\circ}C, I_{TM} = 7 A,$
							Instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	Ι	V <sub>FGT I</sub>	_	—	1.5	V	$Tj=25^{\circ}C,\ V_{D}=6\ V,\ R_{L}=6\ \Omega,$
	II	V <sub>RGT I</sub>		—	1.5	V	R <sub>G</sub> = 330 Ω
	III	V <sub>RGT III</sub>		—	1.5	V	
Gate trigger current <sup>Note2</sup>	Ι	I <sub>FGT I</sub>		—	30	mA	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	I <sub>RGT I</sub>		—	30	mA	R <sub>G</sub> = 330 Ω
	III	I <sub>RGT III</sub>		—	30	mA	
Gate non-trigger voltage		$V_{GD}$	0.2	—	_	V	$Tj = 125^{\circ}C, V_{D} = 1/2 V_{DRM}$
Thermal resistance		R <sub>th(j-c)</sub>		—	3.0	°C/W	Junction to case <sup>Note3</sup>
Critical-rate of rise of off-stat commutating voltage <sup>Note4</sup>	е	(dv/dt)c	5	—	_	V/µs	Tj = 125°C

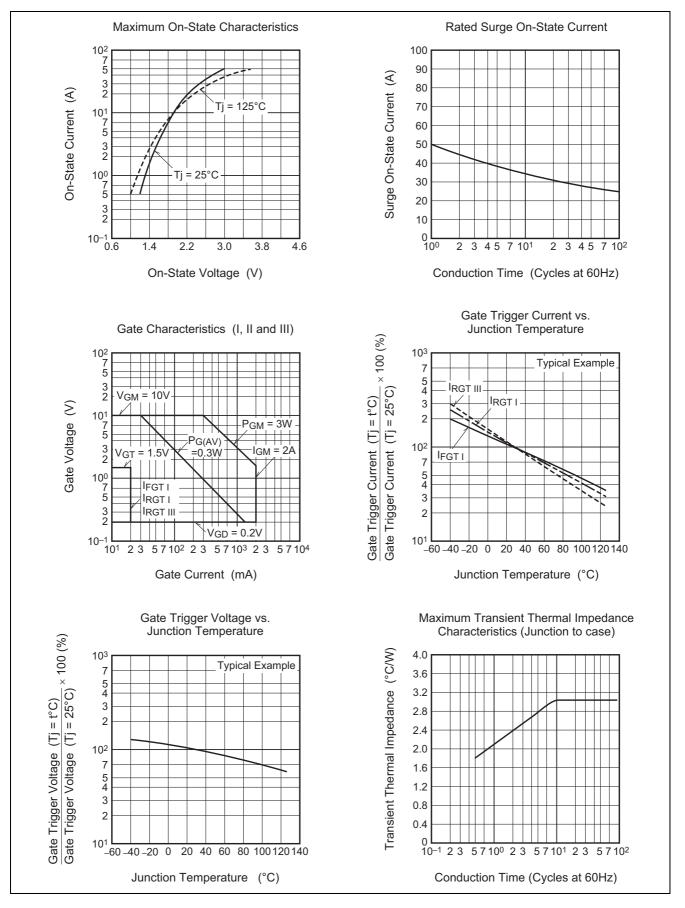
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

3. Case temperature is measured on the  $T_2$  tab.

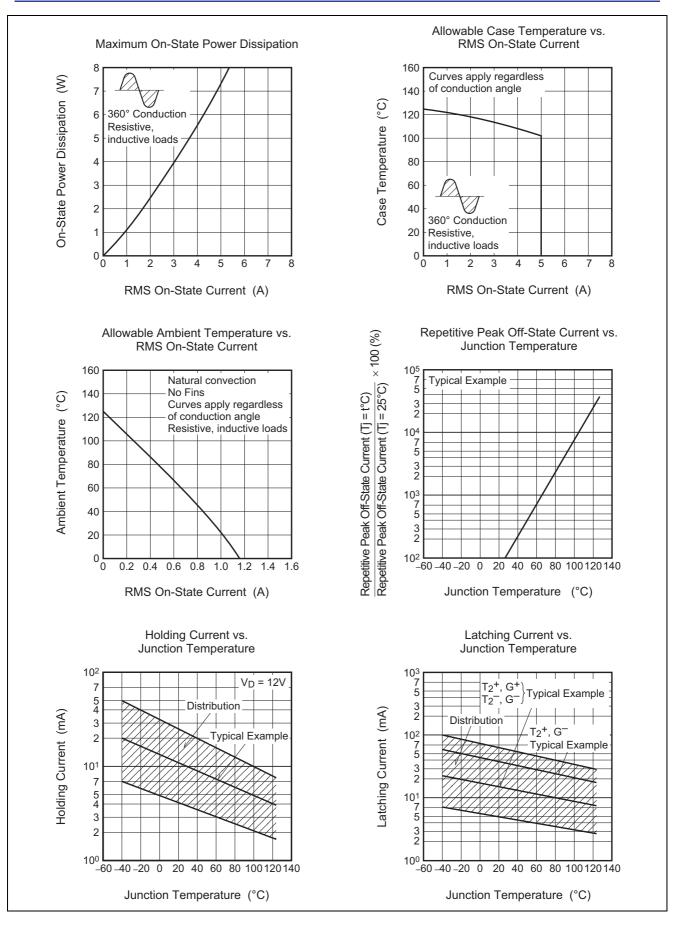
4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125°C	Supply Voltage → Time
<ol> <li>Rate of decay of on-state commutating current (di/dt)c = -2.5 A/ms</li> <li>Peak off-state voltage V<sub>D</sub> = 400 V</li> </ol>	Main Current Main Voltage (dv/dt)c Time VD

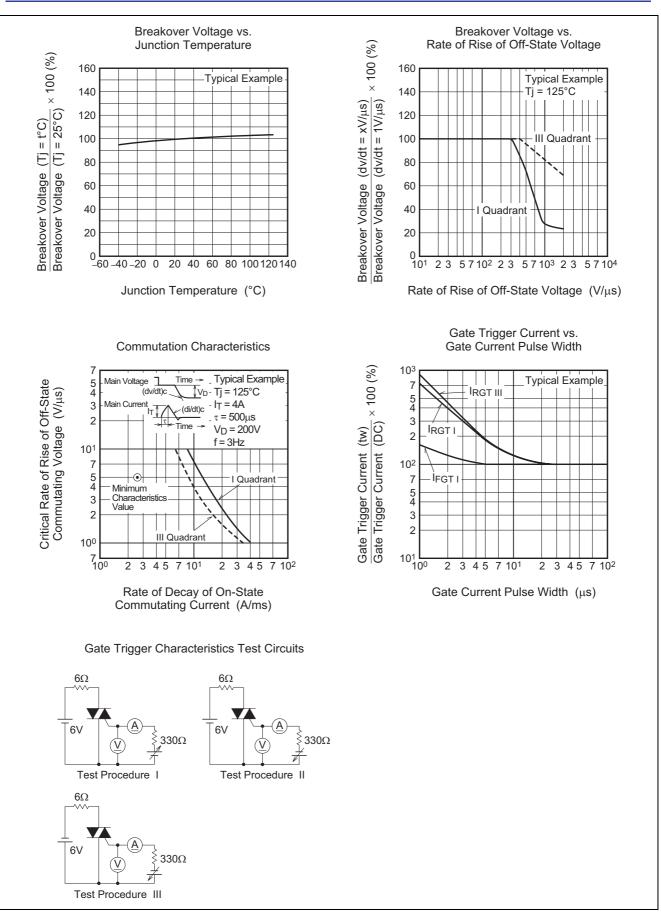
## **Performance Curves**



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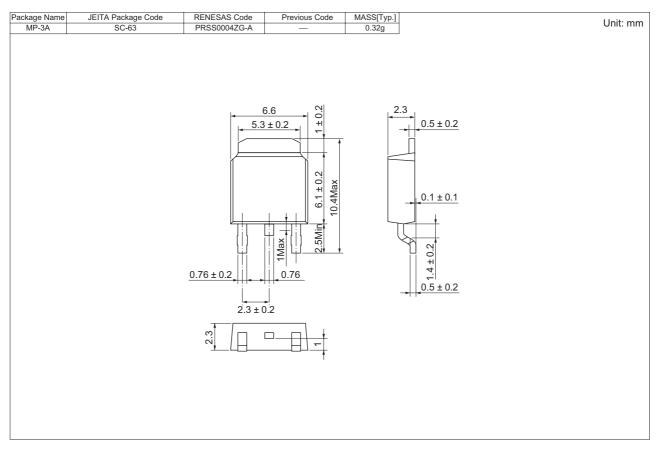


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## **Package Dimensions**



## **Order Code**

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Surface-mounted type	Taping	3000	Type name – T +Direction (1 or 2) +3	BCR5AS-12A-T13
Surface-mounted type	Plastic Magazine (Tube)	75	Type name	BCR5AS-12A

Note : Please confirm the specification about the shipping in detail.

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